

# PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
Name	Execution Date
Wootag Kang	08/05/2009
Jonghae Kim	08/05/2009
<b>RECEIVING PARTY DATA</b>	
Name:	QUALCOMM Incorporated
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State/Country:	CALIFORNIA
Postal Code:	92121-1714
<b>PROPERTY NUMBERS Total: 1</b>	
Property Type	Number
Application Number:	12536819
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ATTORNEY DOCKET NUMBER:	090192
NAME OF SUBMITTER:	Sam Talpalatsky
Total Attachments: 2	
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**PATENT**  
**REEL: 023062 FRAME: 0815**



## ASSIGNMENT

### High Breakdown Voltage Embedded MIM Capacitor Structure

TO WHOM IT MAY CONCERN:

For the sum of One Dollar and other valuable consideration to us in hand paid, receipt of which is hereby acknowledged, be it known that We/I,

1. Wootag Kang, a citizen of United States, having a mailing address of 5775 Morehouse Drive, San Diego, CA 92121; and a resident of San Diego, California.
2. Jonghae Kim, a citizen of Korea, having a mailing address of 5775 Morehouse Drive, San Diego, CA 92121; and a resident of San Diego, California.

have sold, assigned and transferred and by these presents do sell, assign, transfer and set over unto QUALCOMM Incorporated, a Delaware corporation, having a place of business at 5775 Morehouse Drive, San Diego, California 92121-1714, its successors, legal representatives, or assigns, the entire right, title and interest in and to a certain invention relating to **High Breakdown Voltage Embedded MIM Capacitor Structure** by me devised and the application for United States Patent therefore filed in the United States Patent and Trademark Office on 12/536,819, and assigned Serial No. 08/06/09, (and I hereby authorize and instruct QUALCOMM Incorporated to hereafter complete this Assignment by inserting the serial number and date in the space provided above when known), and all original and reissue patents granted thereof, and all divisions, continuations and continuations-in-part thereof, including the subject matter of any and all claims which may be obtained in every such patent, and all foreign rights to said invention, and covenant that I have full right to do so, and agree that I will communicate to said corporation or its representatives all facts known to me respecting said invention, whenever requested, and testify in any legal

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### High Breakdown Voltage Embedded MIM Capacitor Structure

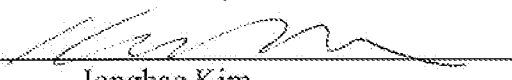
proceedings, sign all lawful papers, make all rightful oaths and generally do everything possible to aid said corporation, its successors, assigns and nominees, to obtain and enforce proper patent protection for said invention in all countries.

The Commissioner of Patents and Trademarks is requested to issue the Letters Patent which may be granted for said invention or any part thereof unto said corporation in keeping with this Assignment.

Done at San Diego, California this 5 day of August, 2009.

  
Wootag Kang

Done at San Diego, California this 5 day of August, 2009.

  
Jonghae Kim